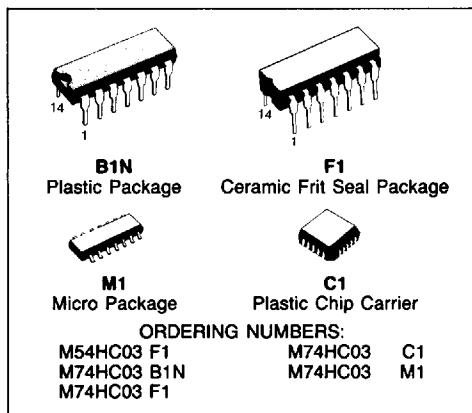


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T-43-2/

QUAD 2-INPUT OPEN DRAIN NAND GATE

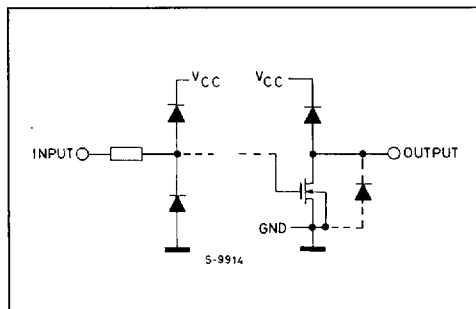
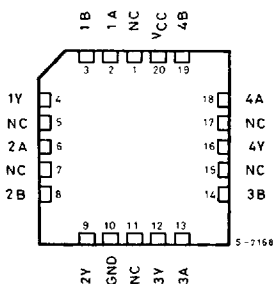
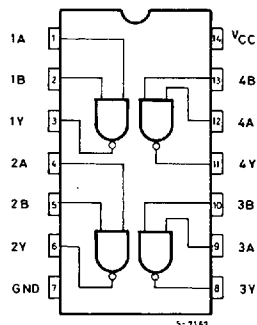
- **LOW POWER DISSIPATION**
 $I_{CC} = 1 \mu A$ (MAX.) at $T_A = 25^\circ C$
- **HIGH NOISE IMMUNITY**
 $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (MIN.)
- **OUTPUT DRIVE CAPABILITY**
 10 LSTTL LOADS
- **SYMMETRICAL OUTPUT IMPEDANCE**
 $|I_{OH}| = I_{OL} = 4 \text{ mA}$ (MIN.)
- **BALANCED PROPAGATION DELAYS**
 $t_{PLH} = t_{PHL}$
- **WIDE OPERATING VOLTAGE RANGE**
 V_{CC} (OPR) = 2V to 6V
- **PIN AND FUNCTION COMPATIBLE**
 WITH 54/74LS03


DESCRIPTION

The M54/74HC03 is a high speed CMOS QUAD 2-INPUT OPEN DRAIN NAND GATE fabricated in silicon gate C²MOS technology.

It has the same high speed performance of LSTTL combined with true CMOS low power consumption.

The internal circuit is composed of 3 stages including buffer output, which gives high noise immunity and stable output. This device can, with an external pull-up resistor, be used in wired AND configuration. This device can be also used as a led driver and in any other application requiring a current sink. All inputs are equipped with protection circuits against static discharge and transient excess voltage.

INPUT AND OUTPUT EQUIVALENT CIRCUIT

PIN CONNECTIONS (top view)


NC =
No Internal
Connection

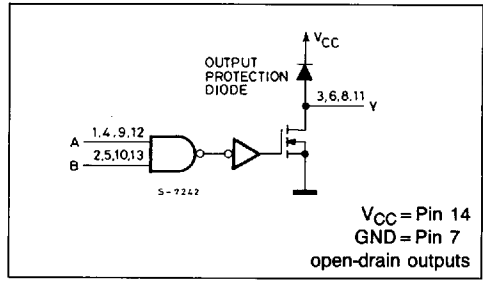
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TRUTH TABLE

INPUTS		OUTPUT
A	B	Y
L	L	Z
L	H	Z
H	L	Z
H	H	L

Z = HIGH IMPEDANCE

CIRCUIT DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage	- 0.5 to 7	V
V _I	DC Input Voltage	- 0.5 to V _{CC} + 0.5	V
V _O	DC Output Voltage	- 0.5 to V _{CC} + 0.5	V
I _{IK}	DC Input Diode Current	± 20	mA
I _{OK}	DC Output Diode Current	± 20	mA
I _O	DC Output Source Sink Current Per Output Pin	± 25	mA
I _{CC} or I _{GND}	DC V _{CC} or Ground Current	± 50	mA
P _D	Power Dissipation	500 (*)	mW
T _{stg}	Storage Temperature	- 65 to 150	°C
T _L	Lead Temperature	300	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

(*) 500 mW: ≅ 65°C derate to 300 mW by 10 mW/°C: 65°C to 85°C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage	2 to 6	V
V _I	Input Voltage	0 to V _{CC}	V
V _O	Output Voltage	0 to V _{CC}	V
T _A	Operating Temperature 74HC Series 54HC Series	- 40 to 85 - 55 to 125	°C
t _r , t _f	Input Rise and Fall Time	V _{CC} { 2 V, 4.5V, 6 V } 0 to 1000 0 to 500 0 to 400	ns

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DC SPECIFICATIONS

Symbol	Parameter	V _{CC}	Test Condition		T _A = 25°C 54HC and 74HC			-40 to 85°C 74HC		-55 to 125°C 54HC		Unit							
					Min.	Typ.	Max.	Min.	Max.	Min.	Max.								
V _{IH}	High Level Input Voltage	2.0			1.5	—	—	1.5	—	1.5	—	V							
		4.5			3.15	—	—	3.15	—	3.15	—								
		6.0			4.2	—	—	4.2	—	4.2	—								
V _{IL}	Low Level Input Voltage	2.0			—	—	0.5	—	0.5	—	0.5	V							
		4.5			—	—	1.35	—	1.35	—	1.35								
		6.0			—	—	1.8	—	1.8	—	1.8								
V _{OL}	Low Level Output Voltage	2.0	V _I	I _O	—	0	0.1	—	0.1	—	0.1	V							
		4.5	V _{IH} or V _{IL}	20 μA									—	0	0.1	—	0.1	—	0.1
		6.0		4.0 mA									—	0.17	0.26	—	0.33	—	0.40
		4.5	V _{IH} or V _{IL}	5.2 mA									—	0.18	0.26	—	0.33	—	0.40
		6.0																	
I _I	Input Leakage Current	6.0	V _{IN} = V _{CC} or GND		—	—	±0.1	—	±1.0	—	±1.0	μA							
I _{OZ}	Output Leakage Current	6.0	V _I = V _{IH} or V _{IL} V _O = V _{CC} or GND		—	—	±0.5	—	±5.0	—	±10								
I _{CC}	Quiescent Supply Current	6.0	V _{IN} = V _{CC} or GND		—	—	1	—	10	—	20	μA							

AC ELECTRICAL CHARACTERISTICS (V_{CC} = 5V, C_L = 15pF, Input t_r = t_f = 6ns T_A = 25°C)

Symbol	Parameter	Test Condition	Min	Typ	Max	Unit
t _{TLH} t _{THL}	Output Transition Time			4	8	ns
t _{PLZ} t _{PZL}	Propagation Delay Time	C _L = 5pF		8	16	ns
		C _L = 15pF		10	20	

AC ELECTRICAL CHARACTERISTICS (C_L = 50pF, Input t_r = t_f = 6ns) S G S-THOMSON

Symbol	Parameter	V _{CC}	Test Condition	T _A = 25°C 54HC and 74HC			-40 to 85°C 74HC		-55 to 125°C 54HC		Unit
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
t _{TLH} t _{THL}	Output Transition Time	2.0 4.5 6.0		— — —	30 8 7	75 15 13	— — —	95 19 16	— — —	110 22 19	ns
t _{PZL} t _{PLZ}	Propagation Delay Time	2.0 4.5 6.0	R _L = 1KΩ	— — —	52 13 11	125 25 21	— — —	155 31 26	— — —	190 38 32	ns
C _{IN}	Input Capacitance			—	5	10	—	10	—	10	pF
C _{OUT}	Output Capacitance			—	5	—	—	—	—	—	pF
C _{PD} (*)	Power Dissipation Capacitance			—	17	—	—	—	—	—	pF

Note (*) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained from the equation:

$$I_{CC(opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ [per Gate]}$$

TYPICAL APPLICATIONS

Wired AND

5-9915

LED Driver with Blanking

5-9916

Typical values
 V_{CC} = 5V
 V_D = 2V
 V_{DS} = 0.4V
 R_D = 120 ÷ 270Ω

I_D = 10 ÷ 20mA

$$R_D = \frac{V_{CC} - V_D - V_{DS}}{I_D} = \frac{5 - 2 - 0.4}{(10 - 20) \cdot 10^{-3}} = 130 \div 260\Omega$$

$$W = Y_1 Y_2 \dots Y_n = \frac{\overline{A_1 B_1} \overline{A_2 B_2} \dots \overline{A_n B_n}}{= A_1 B_1 + A_2 B_2 + \dots + A_n B_n}$$